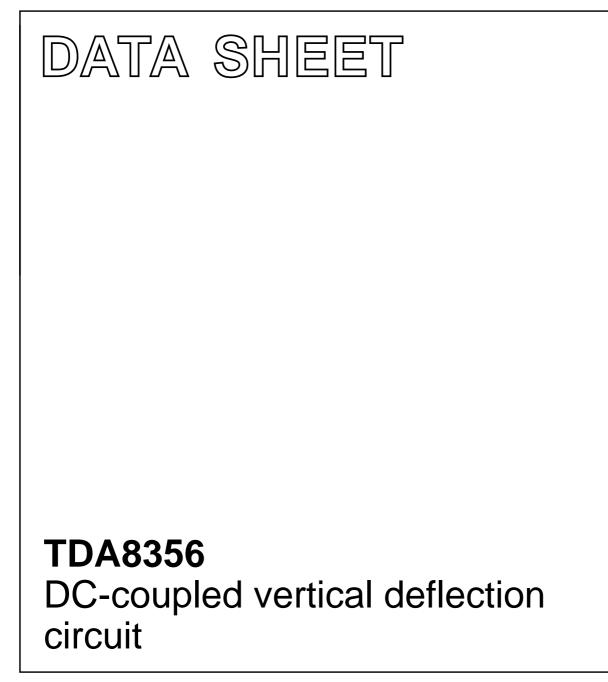
INTEGRATED CIRCUITS



Product specification Supersedes data of 1998 Sep 07 File under Integrated Circuits, IC02 1999 Sep 27



HILIP

TDA8356

FEATURES

- Few external components
- Highly efficient fully DC-coupled vertical output bridge circuit
- Vertical flyback switch
- Guard circuit
- Protection against:
 - Short-circuit of the output pins (7 and 4)
 - $-\,$ Short-circuit of the output pins to $V_{\text{P}}.$
- Temperature protection
- High EMC immunity because of common mode inputs
- A guard signal in zoom mode.

QUICK REFERENCE DATA

GENERAL DESCRIPTION

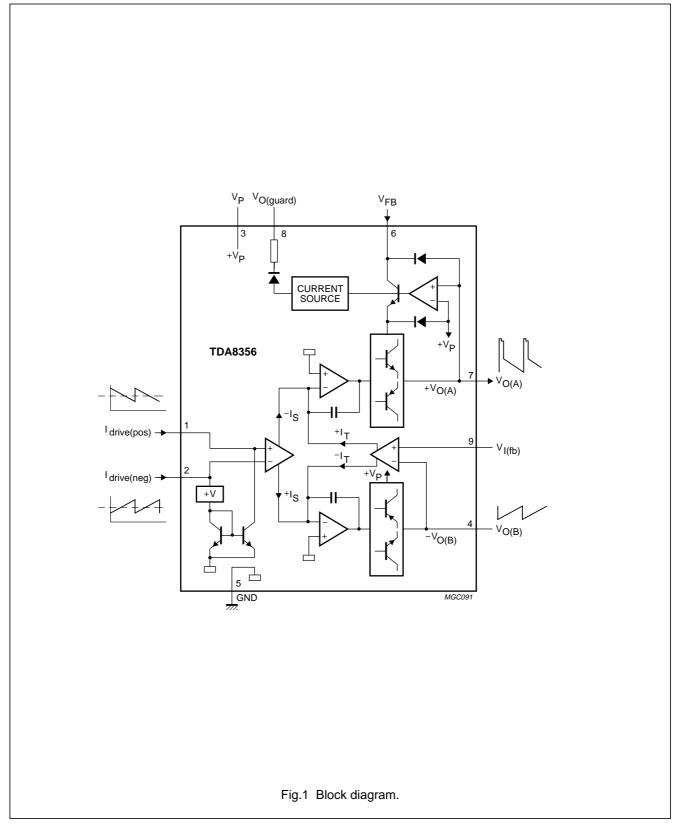
The TDA8356 is a power circuit for use in 90° and 110° colour deflection systems for field frequencies of 50 to 120 Hz. The circuit provides a DC driven vertical deflection output circuit, operating as a highly efficient class G system.

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNIT
DC supply					-
VP	supply voltage	9	14.5	25	V
lq	quiescent supply current	-	30	-	mA
Vertical circuit	t			·	·
I _{O(p-p)}	output current (peak-to-peak value)	_	_	2	A
I _{diff(p-p)}	differential input current (peak-to-peak value)	-	600	-	μA
V _{diff(p-p)}	differential input voltage (peak-to-peak value)	—	1.5	1.8	V
Flyback switcl	h			·	·
I _M peak output current		-	-	±1	А
V _{FB}	flyback supply voltage	-	-	50	V
Thermal data	(in accordance with IEC 747-1)				
T _{stg}	storage temperature	-55	_	+150	°C
T _{amb}	operating ambient temperature	-25	-	+75	°C
T _{vj}	virtual junction temperature	-	-	150	°C

ORDERING INFORMATION

ТҮРЕ		PACKAGE				
NUMBER	NAME	E DESCRIPTION VERS				
TDA8356	SIL9P	plastic single in-line power package; 9 leads	SOT131-2			

BLOCK DIAGRAM



TDA8356

PINNING

SYMBOL	PIN	DESCRIPTION	
I _{drive(pos)}	1	input power-stage (positive); includes I _{I(sb)} signal bias	
I _{drive(neg)}	2	input power-stage (negative); includes I _{I(sb)} signal bias	
V _P	3	operating supply voltage	
V _{O(B)}	4	output voltage B	
GND	5	ground	
V _{FB}	6	input flyback supply voltage	
V _{O(A)}	7	output voltage A	
V _{O(guard)}	8	guard output voltage	
V _{I(fb)}	9	input feedback voltage	

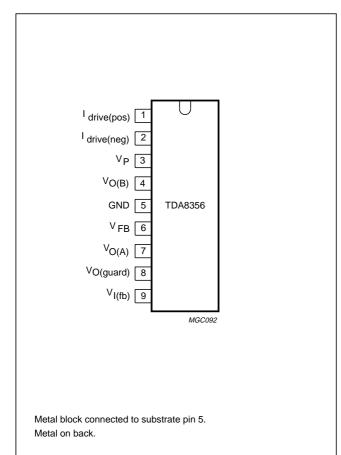


Fig.2 Pin configuration.

FUNCTIONAL DESCRIPTION

The vertical driver circuit is a bridge configuration. The deflection coil is connected between the output amplifiers, which are driven in opposite phase. An external resistor (R_M) connected in series with the deflection coil provides internal feedback information. The differential input circuit is voltage driven. The input circuit has been adapted to enable it to be used with the TDA9150, TDA9151B, TDA9160A, TDA9162, TDA8366 and TDA8376 which deliver symmetrical current signals. An external resistor (R_{CON}) connected between the differential input determines the output current through the deflection coil. The relationship between the differential input current and the output current is defined by: $I_{diff} \times R_{CON} = I_{coil} \times R_{M}$. The output current is adjustable from 0.5 A (p-p) to 2 A (p-p) by varying R_M. The maximum input differential voltage is 1.8 V. In the application it is recommended that $V_{diff} = 1.5 V$ (typ). This is recommended because of the spread of input current and the spread in the value of R_{CON}.

The flyback voltage is determined by an additional supply voltage V_{FB}. The principle of operating with two supply voltages (class G) makes it possible to fix the supply voltage V_P optimum for the scan voltage and the second supply voltage V_{FB} optimum for the flyback voltage. Using this method, very high efficiency is achieved.

The supply voltage V_{FB} is almost totally available as flyback voltage across the coil, this being possible due to the absence of a decoupling capacitor (not necessary, due to the bridge configuration). Built-in protections are:

- Thermal protection
- Short-circuit protection of the output pins (pins 4 and 7)
- Short-circuit protection of the output pins to V_P.

A guard circuit $V_{O(\text{guard})}$ is provided. The guard circuit is activated at the following conditions:

- During flyback
- During short-circuit of the coil and during short-circuit of the output pins (pins 4 and 7) to V_P or ground
- During open loop
- When the thermal protection is activated.

This signal can be used for blanking the picture tube screen.

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
DC supply	· ·			ł	
VP	supply voltage	non-operating	_	40	V
			-	25	V
V _{FB}	flyback supply voltage		_	50	V
Vertical circuit	t .			·	
I _{O(p-p)}	output current (peak-to-peak value)	note 1	-	2	А
V _{O(A)}	output voltage (pin 7)		-	52	V
Flyback switch	1		•		
I _M	peak output current		-	±1.5	А
Thermal data ((in accordance with IEC 747-1)				
T _{stg}	storage temperature		-55	+150	°C
T _{amb}	operating ambient temperature		-25	+75	°C
T _{vj}	virtual junction temperature		-	150	°C
t _{sc}	short-circuiting time	note 2	-	1	hr

Notes

- 1. I_O maximum determined by current protection.
- 2. Up to $V_P = 18 V$.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th vj-c}	thermal resistance vj-case		4	K/W
R _{th vj-a}	thermal resistance vj-ambient	in free air	40	K/W

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CHARACTERISTICS

 V_P = 14.5 V; T_{amb} = 25 °C; V_{FB} = 45 V; f_i = 50 Hz; $I_{I(sb)}$ = 400 μ A; measured in test circuit of Fig.3; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
DC supply	/					1
V _P	operating supply voltage		9.0	14.5	25	V
V _{FB}	flyback supply voltage		VP	-	50	V
I _P	supply current	no signal; no load	_	30	55	mA
Vertical ci	rcuit	1				
V _O	output voltage swing (scan)		13.2	-	_	V
LE	linearity error	I _O = 2 A (p-p); note 1	-	1	4	%
		I _O = 50 mA (p-p); note 1	-	1	4	%
Vo	output voltage swing (flyback); $V_{O(A)} - V_{O(B)}$	$I_{diff} = 0.3 \text{ mA};$ $I_O = 1 \text{ A}$	-	40	-	V
V_{DF}	forward voltage of the internal efficiency diode $(V_{O(A)} - V_{FB})$	$I_{O} = -1 \text{ A};$ $I_{diff} = 0.3 \text{ mA}$	-	-	1.5	V
I _{os}	output offset current	$I_{diff} = 0;$ $I_{I(sb)} = 50 \text{ to } 500 \mu\text{A}$	-	-	40	mA
V _{os}	offset voltage at the input of the feedback amplifier ($V_{I(fb)} - V_{O(B)}$)	$I_{diff} = 0;$ $I_{I(sb)} = 50 \text{ to } 500 \mu\text{A}$	-	-	24	mV
$\Delta V_{\text{os}} T$	output offset voltage as a function of temperature	I _{diff} = 0	-	-	72	μV/K
V _{O(A)}	DC output voltage	I _{diff} = 0; note 2	_	6.5	-	V
G _{vo}	open-loop voltage gain $\left(\frac{V_{7-4}}{V_{1-2}}\right)$	notes 3 and 4	-	80	-	dB
	open loop voltage gain $\left(\frac{V_{7-4}}{V_{9-4}}; V_{1-2} = 0\right)$	note 3	-	80	-	dB
V _R	voltage ratio $\frac{V_{1-2}}{V_{9-4}}$		-	0	-	dB
f _{res}	frequency response (-3 dB)	open loop; note 5	-	40	-	Hz
G _I	current gain (I _O /I _{diff})		_	5000	-	
$\Delta G_c T$	current gain drift as a function of temperature		-	-	10-4	К
I _{I(sb)}	signal bias current		50	400	500	μA
I _{FB}	flyback supply current	during scan	-	-	100	μA
PSRR	power supply ripple rejection	note 6	-	80	-	dB
V _{I(DC)}	DC input voltage		-	2.7	-	V
V _{I(CM)}	common mode input voltage	$I_{I(sb)} = 0$	0	-	1.6	V
I _{bias}	input bias current	$I_{I(sb)} = 0$	-	0.1	0.5	μA
I _{O(CM)}	common mode output current		-	0.2	-	mA

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Guard circ	cuit				•	
I _O	output current	not active; V _{O(guard)} = 0 V	-	-	50	μA
		active; V _{O(guard)} = 3.6 V	1	_	2.5	mA
V _{O(guard)}	output voltage on pin 8	I _O = 100 μA	4.6	-	5.5	V
	allowable voltage on pin 8	maximum leakage current = 10 μ A;	_	-	40	V

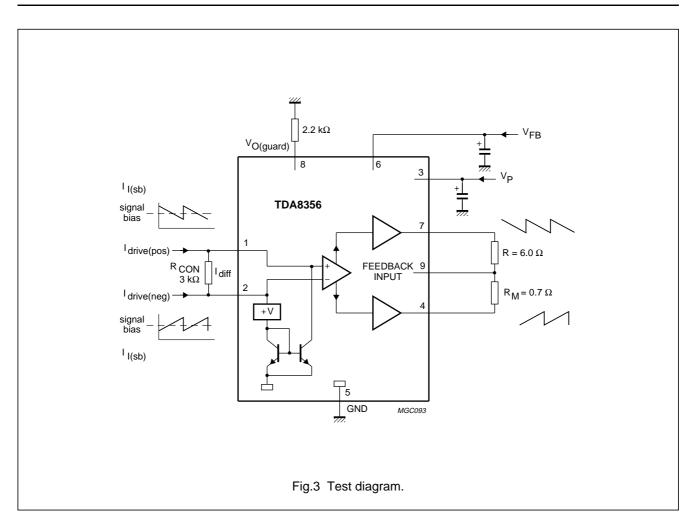
Notes

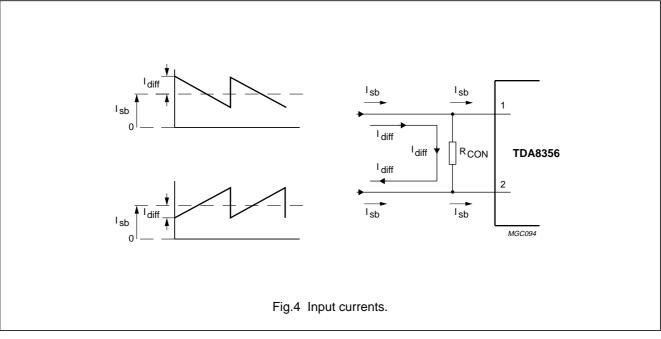
 The linearity error is measured without S-correction and based on the same measurement principle as performed on the screen. The measuring method is as follows: Divide the output signal I₄ – I₇ (V_{RM}) into 22 equal parts ranging from 1 to 22 inclusive. Measure the value of two succeeding parts called one block starting with part 2 and 3 (block 1) and ending with part 20 and 21 (block 10). Thus part 1 and 22 are unused. The equations for linearity error for adjacent blocks (LEAB) and linearity error for not adjacent blocks (LENAB) are given below:

$$\mathsf{LEAB} \,=\, \frac{a_k - a_{(k\,+\,1)}}{a_{avg}} \;; \; \mathsf{LENAB} \,=\, \frac{a_{max} - a_{min}}{a_{avg}}$$

- 2. Related to V_P .
- 3. The V values within formulae relate to voltages at or across relative pin numbers, i.e. V_{7-4}/V_{1-2} = voltage value across pins 7 and 4 divided by voltage value across pins 1 and 2.
- 4. V₉₋₄ AC short-circuited.
- 5. Frequency response V_{7-4}/V_{9-4} is equal to frequency response V_{7-4}/V_{1-2} .
- 6. At $V_{(ripple)}$ = 500 mV eff; measured across R_M ; f_i = 50 Hz.

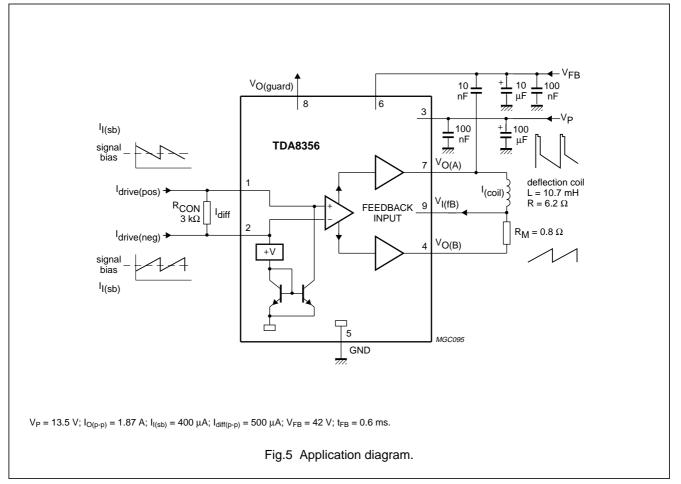
TDA8356





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APPLICATION INFORMATION



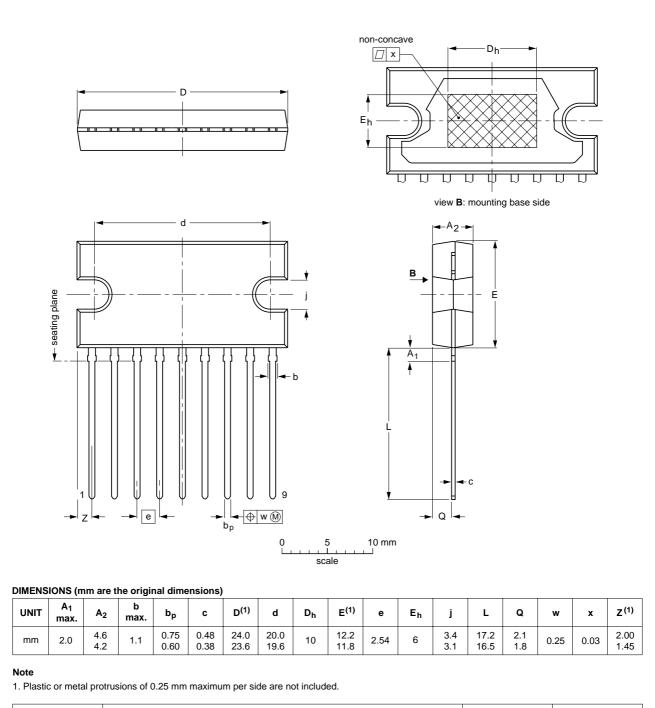
TDA8356

SOT131-2

DC-coupled vertical deflection circuit

PACKAGE OUTLINE

SIL9P: plastic single in-line power package; 9 leads



OUTLINE		REFER	REFERENCES		EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT131-2						-92-11-17 95-03-11

TDA8356

SOLDERING

Introduction to soldering through-hole mount packages

This text gives a brief insight to wave, dip and manual soldering. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (document order number 9398 652 90011).

Wave soldering is the preferred method for mounting of through-hole mount IC packages on a printed-circuit board.

Soldering by dipping or by solder wave

The maximum permissible temperature of the solder is 260 °C; solder at this temperature must not be in contact with the joints for more than 5 seconds.

The total contact time of successive solder waves must not exceed 5 seconds.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified maximum storage temperature ($T_{stg(max)}$). If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

Manual soldering

Apply the soldering iron (24 V or less) to the lead(s) of the package, either below the seating plane or not more than 2 mm above it. If the temperature of the soldering iron bit is less than 300 °C it may remain in contact for up to 10 seconds. If the bit temperature is between 300 and 400 °C, contact may be up to 5 seconds.

Suitability of through-hole mount IC packages for dipping and wave soldering methods

PACKAGE	SOLDERING METHOD			
PACKAGE	DIPPING	WAVE		
DBS, DIP, HDIP, SDIP, SIL	suitable	suitable ⁽¹⁾		

Note

1. For SDIP packages, the longitudinal axis must be parallel to the transport direction of the printed-circuit board.

DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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